

HBPR-200M-30K-SI-FS(T)

High-Speed Balanced Photoreceiver				
Available Input Versions	HBPR-200M-30K-SI-FST 1.035"-40 threaded flange for free space applications, compatible with many optical standard accessories. Optional: Fiber adapters PRA-FC, PRA-FCA, PRA-FSMA \overbrace{vert} Picture shows two 1.035"-40 threaded flanges with internally threaded coupler rings mounted (outer diameter 30 mm)			
	HBPR-200M-30K-SI-FS 25 mm dia. unthreaded flange for free space applications compatible with many optical standard accessories.			
Related Models	Various free space or fiber coupled HBPR models, with bandwidth up to 500 MHz, in the spectral range from 320 nm to 1700 nm are available. Example: FC input fix/permanent FC fiber connector for high coupling efficiency, excellent conversion gain accuracy and common mode rejection ratio (CMRR). See further information and separate datasheets on www.femto.de			
Available Accessories	PRA-FC PRA-FCA PRA-FSMA PRA-FSMA PRA-FSMA PRA-FSMA			
	PS-15 power supply, input: 100 - 240 VAC, output: ±15 VDC, +400/–250 mA			
SOPHISTICATED	TOOLS FOR SIGNAL RECOVERY FENTO			

High-Speed Balanced Photoreceiver

Specifications	Test conditions	$V_{\text{S}}=\pm15$ V, $T_{\text{A}}=25$ °C, signal output terminated with 50 $\Omega,$ Monitor outputs terminated with 1 $M\Omega$	
Gain	Transimpedance gain	10 x 10 ³ V/A (2 nd gain x2), 30 x 10 ³ V/A (2 nd gain x6) switchable (@ 50 Ω load)	
	Gain accuracy	± 1 % electrical	
	Conversion gain	5.4 x 10 ³ V/W typ. (@ 2 nd gain x2, 850 nm) 16.2 x 10 ³ V/W typ. (@ 2 nd gain x6, 850 nm)	
	Common mode rejection ratio (CMRR)	50 dB typ. (f \le 100 MHz) 45 dB typ. (f \le 200 MHz)	
Frequency Response	Lower cut-off frequency	DC / 10 Hz, switchable	
	Upper cut-off frequency	200 MHz, switchable to 20 MHz	
Time Response	Rise/fall time (10 % - 90 %)	1.75 ns (@ 2 nd gain x2); 1.85 ns (@ 2 nd gain x6) 17.5 ns (low pass filter 20 MHz)	
Input	Noise equivalent power (NEP)	minimum 7.8 pW/√Hz (@ 850 nm) 8.8 pW/√Hz (@ 850 nm, 20 MHz) 19.0 pW/√Hz (@ 850 nm, 100 MHz) 33.0 pW/√Hz (@ 850 nm, 200 MHz)	
	Maximum differential CW power for linear amplification	185 μW (@ 2 nd gain x2, DC-coupled, 850 nm) 62 μW (@ 2 nd gain x6, DC-coupled, 850 nm) 850 μW (@ AC-coupled, 850 nm)	
	Max. optical CW balanced power (common mode power)	10 mW (on each photodiode, @ 850 nm)	
	Monitor optical saturation power (limited by Maximum Rating)	12 mW (@ 850 nm)	
Detector	Detector	SI-PIN photodiode	
	Active area	Ø 800 µm	
	Spectral range	320 - 1000 nm	
	Sensitivity	0.54 A/W typ. (@ 850 nm)	
Signal Output	Output voltage range	± 1.0 V (@ 50 Ω load) for linear operation and low harmonic distortion	
	Max. output voltage	±2.0 V (@ 50 Ω load)	
	Offset voltage compensation	± 100 mV typ., adjustable by offset potentiometer	
	Output impedance	50 Ω (terminate with 50 Ω load)	
	Slew rate	2800 V/µs	
	Max. output current	70 mA	
	Output return loss S22	−30 dB @ < 100 MHz −20 dB @ < 800 MHz	
	Output noise	2.0 mV _{RMS} (13 mV _{PP}) (@ 2^{nd} gain x2) 5.5 mV _{RMS} (36 mV _{PP}) (@ 2^{nd} gain x6) 0.3 mV _{RMS} (2.0 mV _{PP}) typ. (@ 2^{nd} gain x2, BW: 20 MHz) 0.8 mV _{RMS} (5.3 mV _{PP}) typ. (@ 2^{nd} gain x6, BW: 20 MHz) (@ 50 Ω load, no signal on detectors, measurement bandwidth 2 GHz)	
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Specifications (Continued)					
Monitor Outputs	Monitor output gain	$1 \ge 10^3 \text{ V/A} \ (@ \ge 10)$	$0 \ \mathrm{k}\Omega$ load)		
	Monitor output voltage range	$0 \ \ +10 \ \text{V}$ (@ $\geq 100 \ \text{k}\Omega$ load)			
	Monitor output impedance	50 Ω (terminate with	50 Ω (terminate with \geq 100 k Ω load)		
	Monitor output max. output current	30 mA typ.			
	Monitor output bandwidth	DC 10 MHz			
	Monitor output noise	0.6 mV _{RMS} (4 mV _{PP}) (@ 100 k Ω load, no signal on detectors, measurement bandwidth 200 MHz)			
Input Flange	Material	1.4305 stainless steel, nickel-plated (FST flange) AIMg4.5Mn, nickel-plated (FS flange)			
Coupler Ring (FST version only)	Material	1.4305 stainless steel, glass bead blasted			
Power Supply	Supply voltage	±15 V (±14.5 V ±	±15 V (±14.5 V ±16.5 V)		
	Supply current	-90 / $+120$ mA (depends on operating conditions, recommended power supply capability min. ± 200 mA)			
Case	Weight	410 g (0.9 lbs)	410 g (0.9 lbs)		
	Material	AlMg3Mn, nickel-pla	AIMg3Mn, nickel-plated		
Temperature Range	Storage temperature	−40 +85 °C			
	Operating temperature	0 +60 °C			
Absolute Maximum Ratings	Max. CW power (averaged)	12 mW (on each photodiode)			
	Power supply voltage	±20 V			
Connectors	Input	FS version	25 mm dia. unthreaded flange for free space applications		
		FST version	1.035"-40 threaded flange for free space applications and for use with various types of optical standard accessories		
	Output	SMA jack (female)			
	Power supply	Lemo [®] series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)			
	P -\ -\	IN 2 O O PIN S O O PIN PIN GNI	_1 Pin 1: +15 V Pin 2: −15 V Pin 3: GND		
Scope of Delivery	HBPR-200M-30K-SI, 2 x threaded coupler ring (FST version only), Lemo® 3-pin connector, 3 x adapter SMA (male) to BNC (female), datasheet				
Ordering Information	HBPR-200M-30K-SI-FS	25 mm dia. unthreaded flange for free space applications			
	HBPR-200M-30K-SI-FST	1.035"-40 threaded flange for free space applications and for use with various types of optical standard accessories			





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